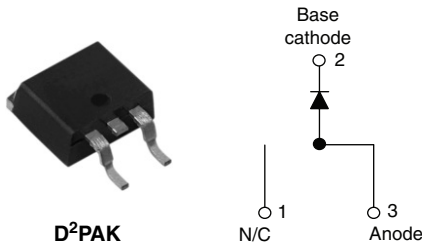


## Schottky Rectifier, 10 A



### FEATURES

- 175 °C  $T_J$  operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified for Q101 level

### DESCRIPTION

The 10TQ...S Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### PRODUCT SUMMARY

$I_{F(AV)}$	10 A
$V_R$	35/45 V

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	10	A
$V_{RRM}$		35/45	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	1050	A
$V_F$	10 Apk, $T_J = 125 \text{ }^\circ\text{C}$	0.49	V
$T_J$	Range	- 55 to 175	$^\circ\text{C}$

### VOLTAGE RATINGS

PARAMETER	SYMBOL	10TQ035S	10TQ045S	UNITS
Maximum DC reverse voltage	$V_R$	35	45	V
Maximum working peak reverse voltage	$V_{RWM}$			

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at $T_C = 151 \text{ }^\circ\text{C}$ , rectangular waveform	10	A
Maximum peak one cycle non-repetitive surge current See fig. 7	$I_{FSM}$	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	1050	A
		10 ms sine or 6 ms rect. pulse		
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25 \text{ }^\circ\text{C}$ , $I_{AS} = 2 \text{ A}$ , $L = 6.5 \text{ mH}$	13	mJ
Repetitive avalanche current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical	2	A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	10 A	$T_J = 25\text{ }^\circ\text{C}$	0.57	V
		20 A		0.67	
		10 A	$T_J = 125\text{ }^\circ\text{C}$	0.49	
		20 A		0.61	
Maximum reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	2	mA
		$T_J = 125\text{ }^\circ\text{C}$		15	
Maximum junction capacitance	$C_T$	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		900	pF
Typical series inductance	$L_S$	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	$dV/dt$	Rated $V_R$		10 000	V/ $\mu$ s

**Note**(1) Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$			- 55 to 175	$^\circ\text{C}$
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation See fig. 4		2.0	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth and greased		0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device		Case style D <sup>2</sup> PAK		10TQ035S	
				10TQ045S	

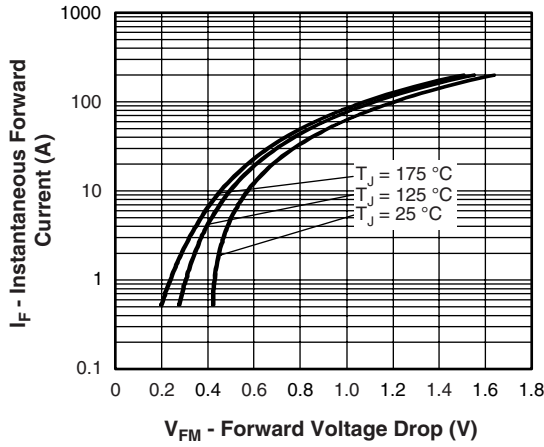


Fig. 1 - Maximum Forward Voltage Drop Characteristics

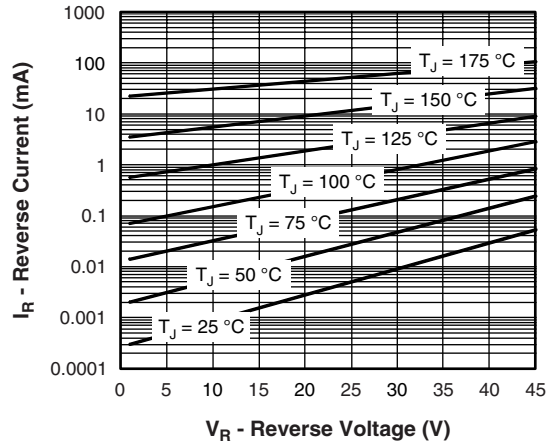


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

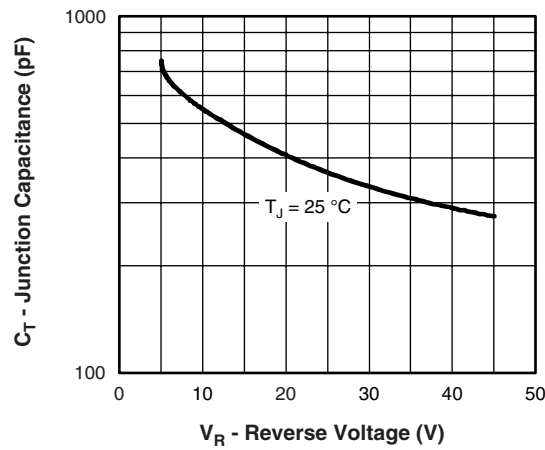


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

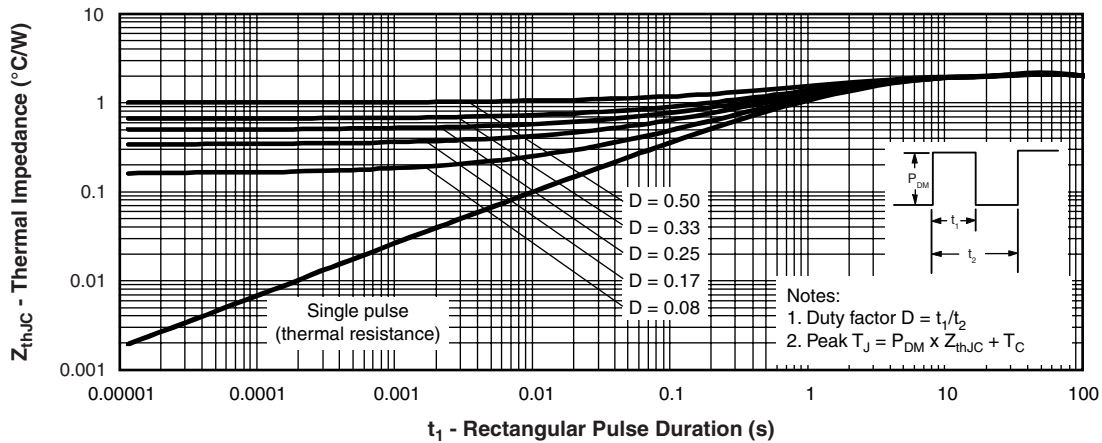


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

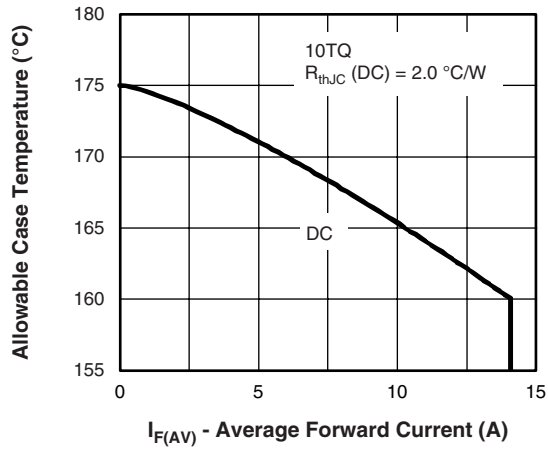


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

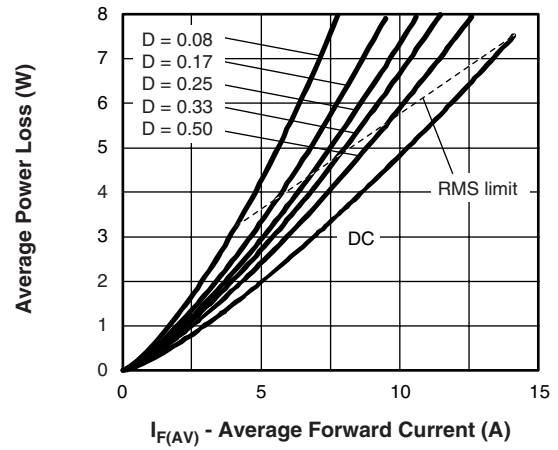


Fig. 6 - Forward Power Loss Characteristics

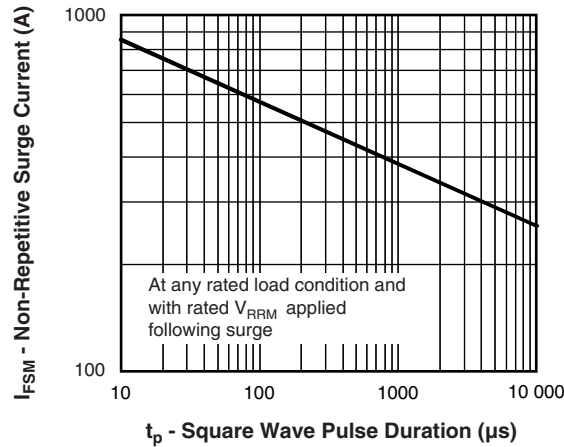


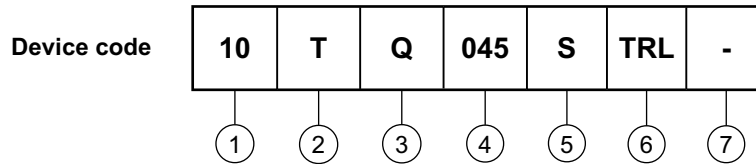
Fig. 7 - Maximum Non-Repetitive Surge Current



Fig. 8 - Unclamped Inductive Test Circuit



**ORDERING INFORMATION TABLE**



- 1** - Current rating (10 A)
- 2** - Circuit configuration:  
T = TO-220
- 3** - Schottky "Q" series
- 4** - Voltage ratings 

035 = 35 V
045 = 45 V
- 5** -
  - S = D<sup>2</sup>PAK
- 6** -
  - None = Tube (50 pieces)
  - TRL = Tape and reel (left oriented)
  - TRR = Tape and reel (right oriented)
- 7** -
  - None = Standard production
  - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95014">http://www.vishay.com/doc?95014</a>
Part marking information	<a href="http://www.vishay.com/doc?95008">http://www.vishay.com/doc?95008</a>
Packaging information	<a href="http://www.vishay.com/doc?95032">http://www.vishay.com/doc?95032</a>



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